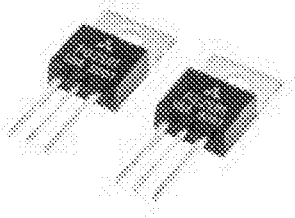


FS2UM-18A

HIGH-SPEED SWITCHING USE

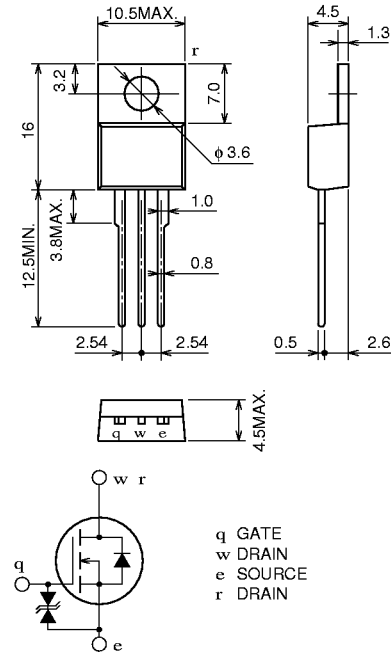
FS2UM-18A



ˆ V _{DSS}	900V
ˆ r _{DS (ON)} (MAX)	7.3Ω
ˆ I _D	2A

OUTLINE DRAWING

Dimensions in mm



TO-220

APPLICATION

SMPS, DC-DC Converter, battery charger, power supply of printer, copier, HDD, FDD, TV, VCR, personal computer etc.

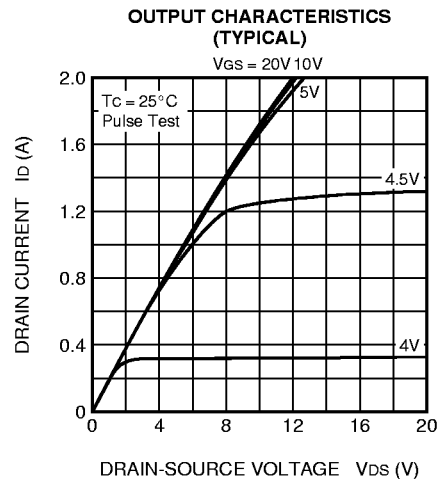
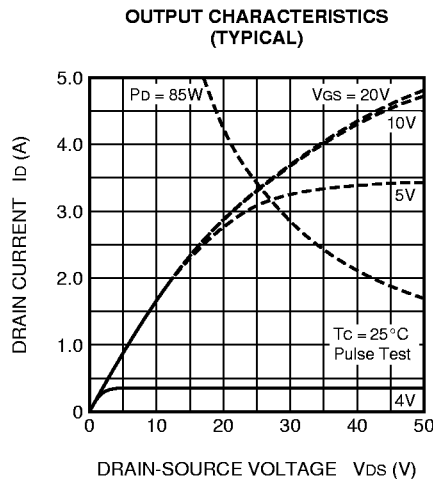
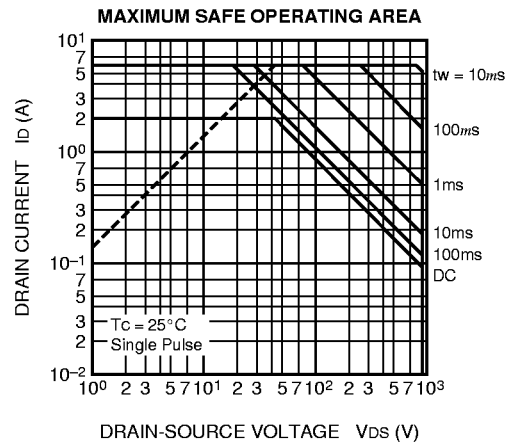
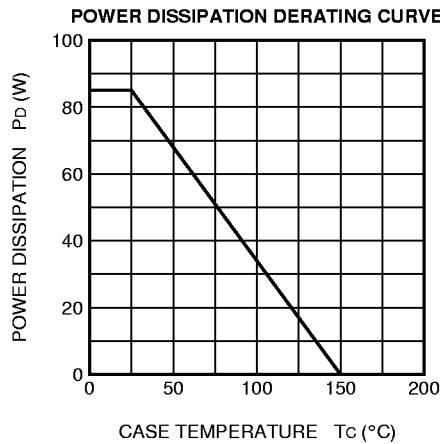
MAXIMUM RATINGS (T_c = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{DSS}	Drain-source voltage	V _{GS} = 0V	900	V
V _{GSS}	Gate-source voltage	V _{DS} = 0V	±30	V
I _D	Drain current		2	A
I _{DM}	Drain current (Pulsed)		6	A
P _D	Maximum power dissipation		85	W
T _{ch}	Channel temperature		-55 ~ +150	°C
T _{stg}	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	2	g

ELECTRICAL CHARACTERISTICS (T_{ch} = 25 °C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	I _D = 1mA, V _{GS} = 0V	900	—	—	V
V (BR) GSS	Gate-source breakdown voltage	I _{GS} = ±100μA, V _{DS} = 0V	±30	—	—	V
I _{GSS}	Gate-source leakage current	V _{GS} = ±25V, V _{DS} = 0V	—	—	±10	μA
I _{DSS}	Drain-source leakage current	V _{DS} = 900V, V _{GS} = 0V	—	—	1	mA
V _{GS} (th)	Gate-source threshold voltage	I _D = 1mA, V _{DS} = 10V	2	3	4	V
r _{DS} (ON)	Drain-source on-state resistance	I _D = 1A, V _{GS} = 10V	—	5.62	7.30	Ω
V _{DS} (ON)	Drain-source on-state voltage	I _D = 1A, V _{GS} = 10V	—	5.62	7.30	V
y _{fs}	Forward transfer admittance	I _D = 1A, V _{DS} = 10V	1.2	2.0	—	S
C _{iss}	Input capacitance	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz	—	460	—	pF
C _{oss}	Output capacitance		—	45	—	pF
C _{rss}	Reverse transfer capacitance		—	8	—	pF
t _d (on)	Turn-on delay time	V _{DD} = 200V, I _D = 1A, V _{GS} = 10V, R _{GEN} = R _{GS} = 50Ω	—	11	—	ns
t _r	Rise time		—	13	—	ns
t _d (off)	Turn-off delay time		—	55	—	ns
t _f	Fall time		—	22	—	ns
V _{SD}	Source-drain voltage	I _S = 1A, V _{GS} = 0V	—	1.0	1.5	V
R _{th} (ch-c)	Thermal resistance	Channel to case	—	—	1.47	°C/W

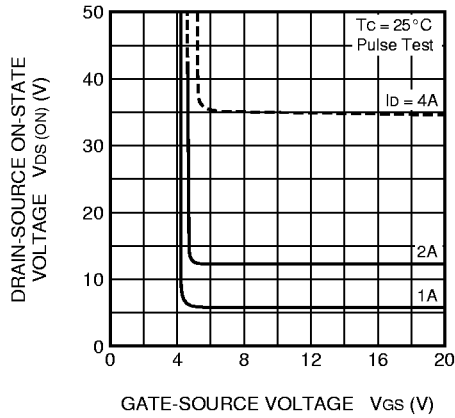
PERFORMANCE CURVES



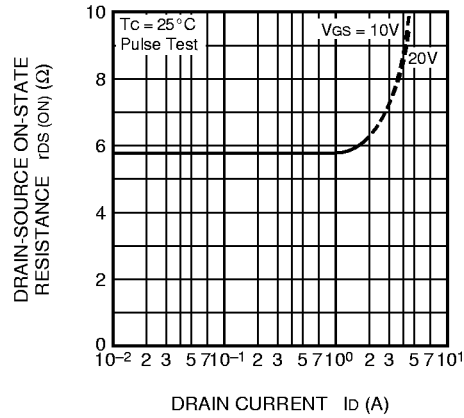
FS2UM-18A

HIGH-SPEED SWITCHING USE

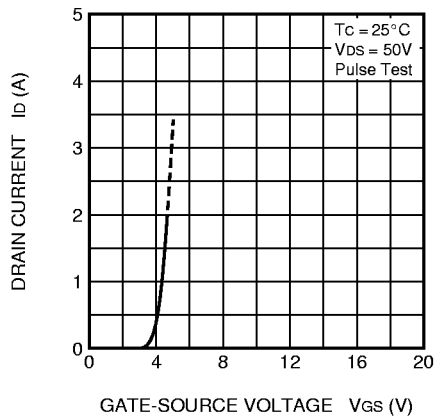
ON-STATE VOLTAGE VS.
GATE-SOURCE VOLTAGE
(TYPICAL)



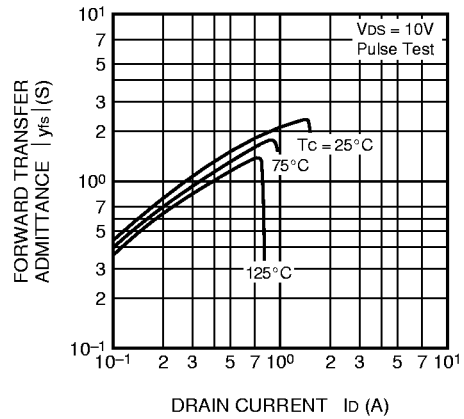
ON-STATE RESISTANCE VS.
DRAIN CURRENT
(TYPICAL)



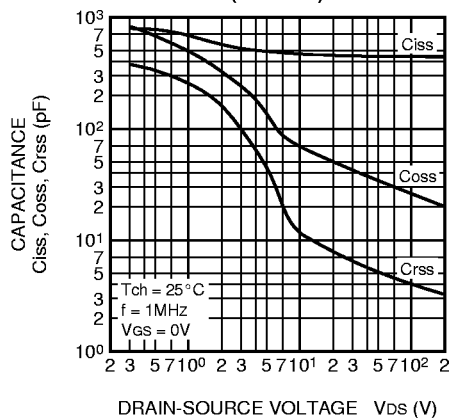
TRANSFER CHARACTERISTICS
(TYPICAL)



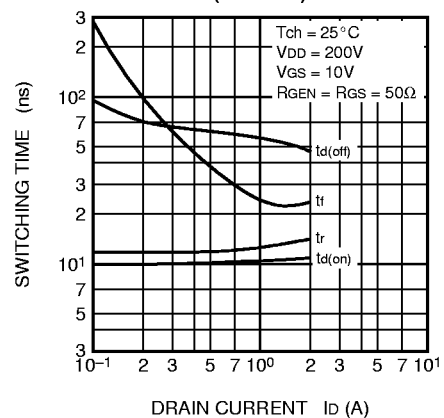
FORWARD TRANSFER ADMITTANCE
VS. DRAIN CURRENT
(TYPICAL)



CAPACITANCE VS.
DRAIN-SOURCE VOLTAGE
(TYPICAL)



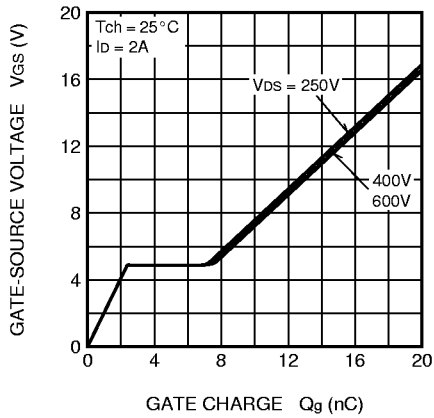
SWITCHING CHARACTERISTICS
(TYPICAL)



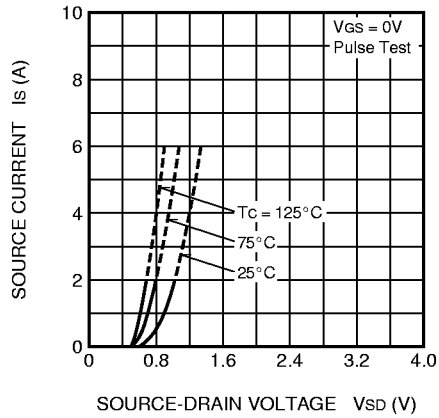
FS2UM-18A

HIGH-SPEED SWITCHING USE

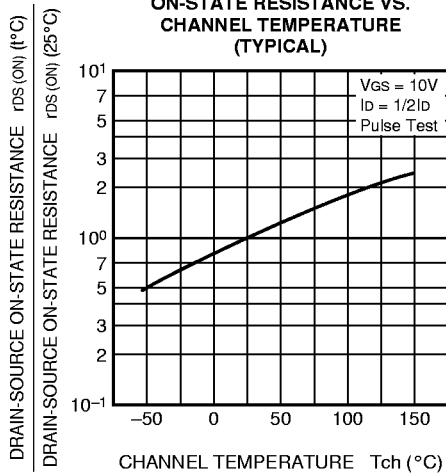
**GATE-SOURCE VOLTAGE
VS. GATE CHARGE
(TYPICAL)**



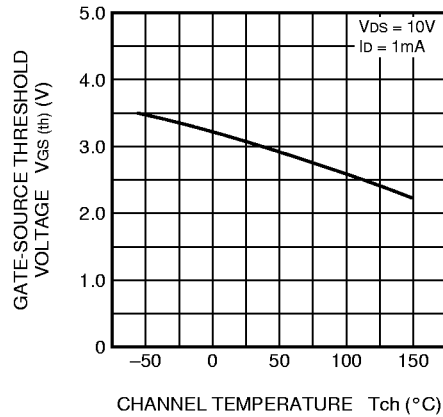
**SOURCE-DRAIN DIODE
FORWARD CHARACTERISTICS
(TYPICAL)**



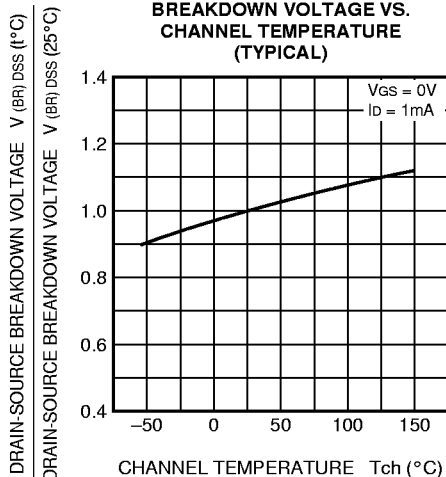
**ON-STATE RESISTANCE VS.
CHANNEL TEMPERATURE
(TYPICAL)**



**THRESHOLD VOLTAGE VS.
CHANNEL TEMPERATURE
(TYPICAL)**



**BREAKDOWN VOLTAGE VS.
CHANNEL TEMPERATURE
(TYPICAL)**



**TRANSIENT THERMAL IMPEDANCE
CHARACTERISTICS**

